






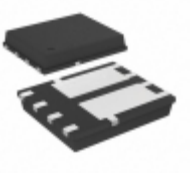
	<p>SI7880ADP-T1-E3</p>
	<p>Hersteller-Teilenummer: SI7880ADP-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 40A PPAK SO-8</p> <p>Datenblätter:  SI7880ADP-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 101189 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7880ADP-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 40A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	101189 pcs Stock
Hersteller Standard Vorlaufzeit	27 Weeks
detaillierte Beschreibung	N-Channel 30V 40A (Tc) 5.4W (Ta), 83W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	5.4W (Ta), 83W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	40A (Tc)
Rds On (Max) @ Id, Vgs	3 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	125nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	5600pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI7880ADP-T1-E3DKR

SI7880ADP-T1-E3 ist neu im Original. Suche SI7880ADP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7880ADP-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7880ADP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7880ADP SI SI7880ADP SI</p>	 <p>SI7880DP-T1 VISHAY SI7880DP-T1 VISHAY</p>	 <p>SI7880DP-T1-E3 VISHAY SI7880DP-T1-E3 VISHAY</p>	 <p>SI7880DP VISHAY VISHAY QFN</p>
 <p>SI7880ADP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7880ADP-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7880ADP-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 40A PPAK SO-8</p>	 <p>SI7872DP-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 6.4A PPAK SO-8</p>

heiße Teile

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|  SI7864DP-T1-GE3 |  SI7866ADP |  SI7866ADP-T1-E3 |  SI7866ADP-T1-E3 |  SI7866ADP-T1-GE3 |
|  SI7866ADP-T1-GE3 |  SI7866DP-T1 |  SI7866DP-T1-E3 |  SI7866DP-T1-GE3 |  SI7868ADP |
|  SI7868ADP-T1-E3 |  SI7868ADP-T1-E3 |  SI7868ADP-T1-GE3 |  SI7868ADP-T1-GE3 |  SI7868DP-T1 |
|  SI7868DP-T1-E3 |  SI7868DP-T1-GE3 |  SI7868DP-T1-GE3 |  SI7868DP-T1-GE3 |  SI7872DP |
|  SI7872DP-T1-E3 |  SI7872DP-T1-E3 |  SI7872DP-T1-GE3 |  SI7872DP-T1-GE3 |  SI7880ADP-T1-E3 |
|  SI7880ADP-T1-GE3 |  SI7880ADP-T1-GE3 |  SI7880ADP-T1-GE3 |  SI7882DP-T1-E3 |  SI7882DP-T1-E3 |
|  SI7882DP-T1-GE3 |  SI7882DP-T1-GE3 |  SI7884BDP |  SI7884BDP-T1-E3 |  SI7884BDP-T1-E3 |
|  SI7884BDP-T1-GE3 |  SI7884BDP-T1-GE3 |  SI7884DP-T1-E3 |  SI7884DP-T1-GE3 |  SI7886ADP-T1-E3 |
|  SI7886ADP-T1-E3 |  SI7886ADP-T1-GE3 |  SI7886ADP-T1-GE3 |  SI7886DP |  SI7886DP-T1 |
|  SI7886DP-T1-E3 |  SI7886DP-T1-GE3 |  SI7888DP-T1-E3 |  SI7888DP-T1-E3 |  SI7888DP-T1-GE3 |

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